

# PUMH20,115 Datasheet

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DiGi Electronics Part Number	PUMH20,115-DG
Manufacturer	<a href="#">Nexperia USA Inc.</a>
Manufacturer Product Number	PUMH20,115
Description	TRANS PREBIAS 2NPN 50V 6TSSOP
Detailed Description	Pre-Biased Bipolar Transistor (BJT) 2 NPN - Pre-Biased (Dual) 50V 100mA 300mW Surface Mount 6-TSSOP



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## Purchase and inquiry

Manufacturer Product Number:

PUMH20,115

Series:

-

Transistor Type:

2 NPN - Pre-Biased (Dual)

Voltage - Collector Emitter Breakdown (Max):

50V

Resistor - Emitter Base (R2):

2.2kOhms

Vce Saturation (Max) @ Ib, Ic:

150mV @ 500µA, 10mA

Frequency - Transition:

-

Grade:

Automotive

Mounting Type:

Surface Mount

Supplier Device Package:

6-TSSOP

Manufacturer:

Nexperia USA Inc.

Product Status:

Active

Current - Collector (Ic) (Max):

100mA

Resistor - Base (R1):

2.2kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

30 @ 20mA, 5V

Current - Collector Cutoff (Max):

1µA

Power - Max:

300mW

Qualification:

AEC-Q100

Package / Case:

6-TSSOP, SC-88, SOT-363

Base Product Number:

PUMH20

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



# PUMH20

50 V, 100 mA NPN/NPN resistor-equipped double transistor;  
 $R1 = 2.2 \text{ k}\Omega$ ,  $R2 = 2.2 \text{ k}\Omega$

16 May 2023

Product data sheet

## 1. General description

NPN/NPN double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD20

PNP/PNP complement: PUMB20

## 2. Features and benefits

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

## 3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replacement of general-purpose transistors in digital applications

## 4. Quick reference data

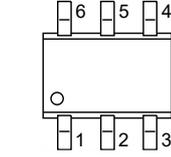
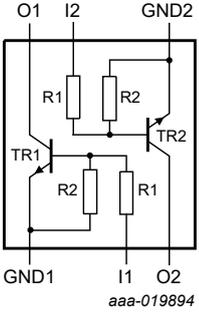
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
$I_O$	output current		-	-	100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	$\text{k}\Omega$
R2/R1	bias resistor ratio		0.8	1	1.2	

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k $\Omega$ , R2 = 2.2 k $\Omega$ 

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p>TSSOP6 (SOT363)</p>	 <p>aaa-019894</p>
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
<a href="#">PUMH20</a>	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<a href="#">SOT363</a>

## 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMH20	H7%

[1] % = placeholder for manufacturing site code

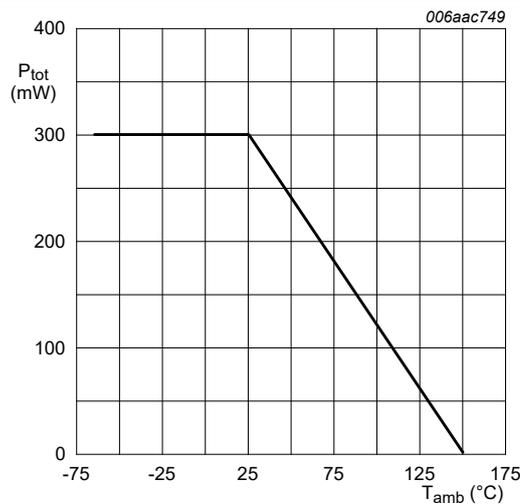
50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k $\Omega$ , R2 = 2.2 k $\Omega$ 

## 8. Limiting values

**Table 5. Limiting values**
*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions		Min	Max	Unit
<b>Per transistor</b>						
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
V <sub>I</sub>	input voltage			-10	12	V
I <sub>O</sub>	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
<b>Per device</b>						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35  $\mu$ m copper, tin-plated and standard footprint

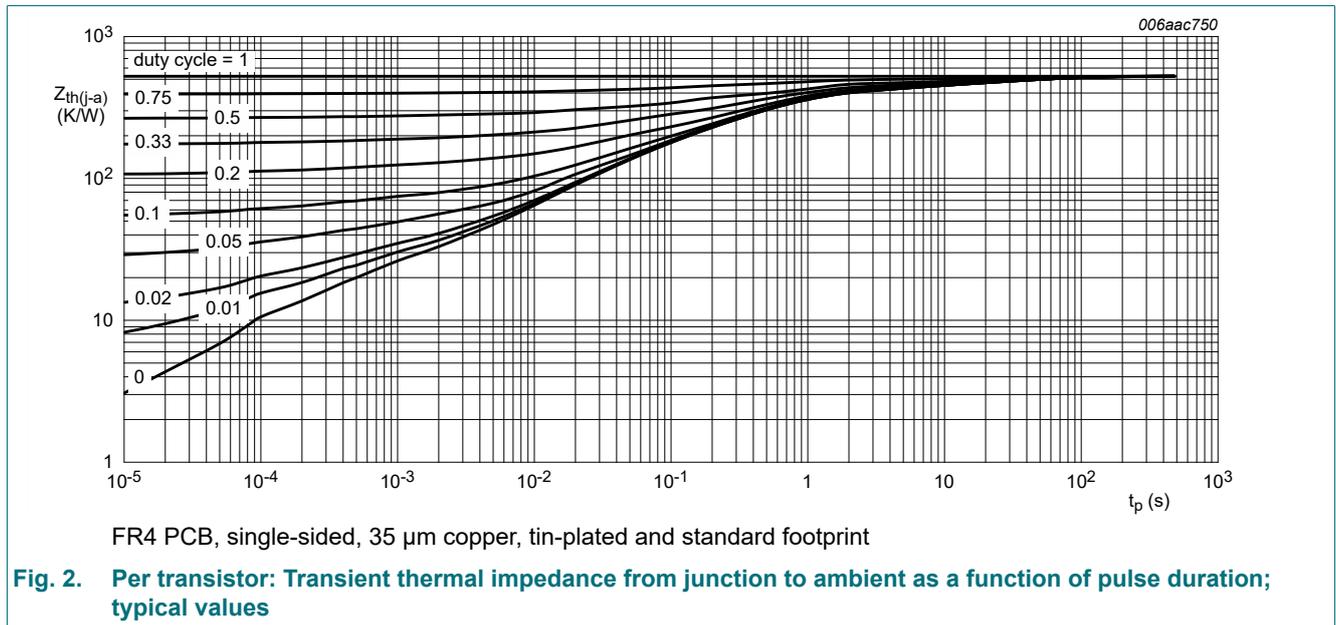
**Fig. 1. Per device: Power derating curve**

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

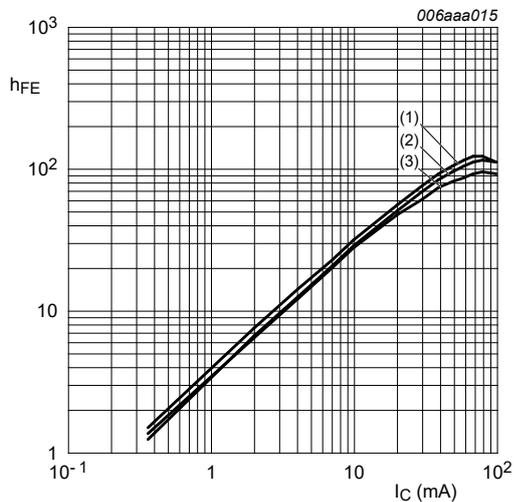
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



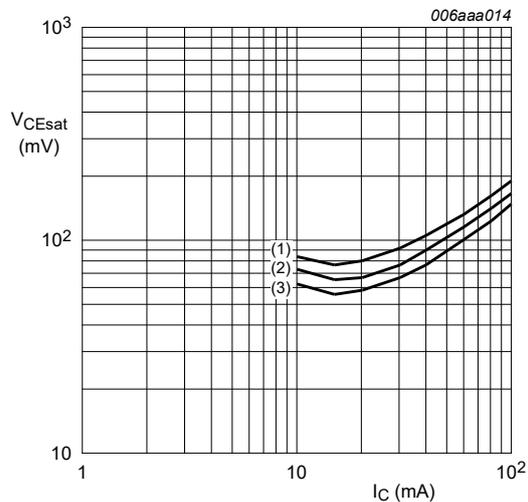
## 10. Characteristics

**Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu\text{A}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 50 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA
		$V_{CE} = 30 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_j = 150 \text{ }^\circ\text{C}$	-	-	5	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5 \text{ V}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	2	mA
$h_{FE}$	DC current gain	$V_{CE} = 5 \text{ V}$ ; $I_C = 20 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	30	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10 \text{ mA}$ ; $I_B = 0.5 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}$ ; $I_C = 1 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	1.2	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}$ ; $I_C = 20 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	2	1.6	-	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	k $\Omega$
R2/R1	bias resistor ratio		0.8	1	1.2	
$C_c$	collector capacitance	$V_{CB} = 10 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	2.5	pF



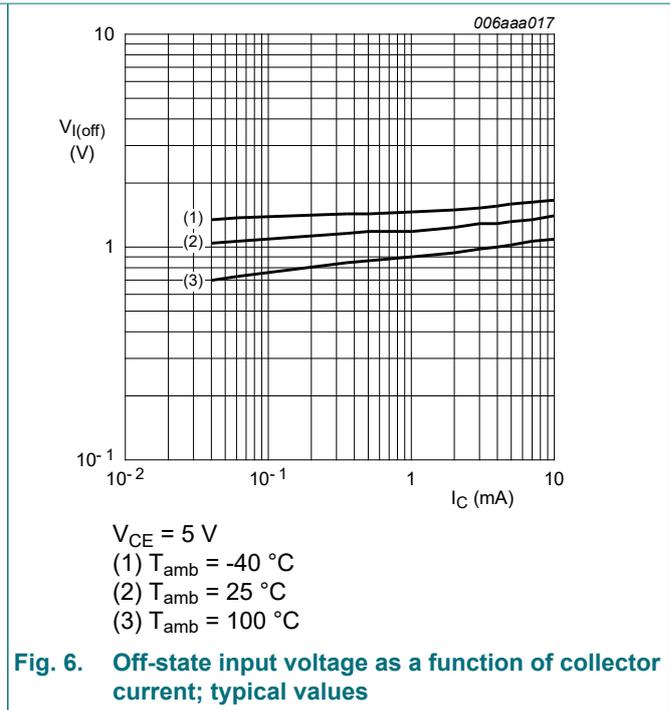
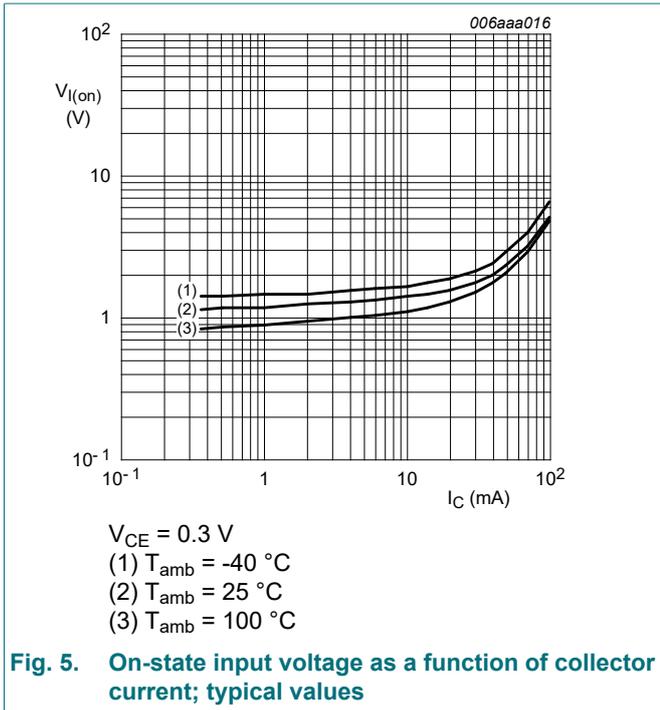
$V_{CE} = 5 \text{ V}$   
 (1)  $T_{\text{amb}} = 150 \text{ }^\circ\text{C}$   
 (2)  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{\text{amb}} = -40 \text{ }^\circ\text{C}$

**Fig. 3. DC current gain as a function of collector current; typical values**


$I_C/I_B = 20$   
 (1)  $T_{\text{amb}} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{\text{amb}} = -40 \text{ }^\circ\text{C}$

**Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values**

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 kΩ, R2 = 2.2 kΩ



## 11. Test information

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R_2}{R_1} = \frac{V(I_4) - V(I_3)}{R_1 \cdot (I_4 - I_3)} - 1$$

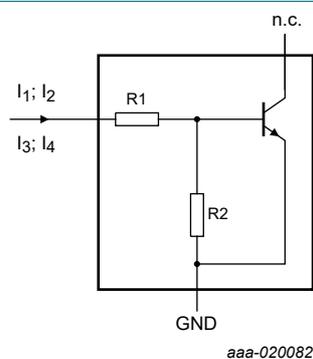


Fig. 7. Per transistor: Resistor test circuit

### Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	I <sub>4</sub>
PUMH20	2.2	2.2	750 μA	950 μA	-750 μA	-950 μA

## 12. Package outline

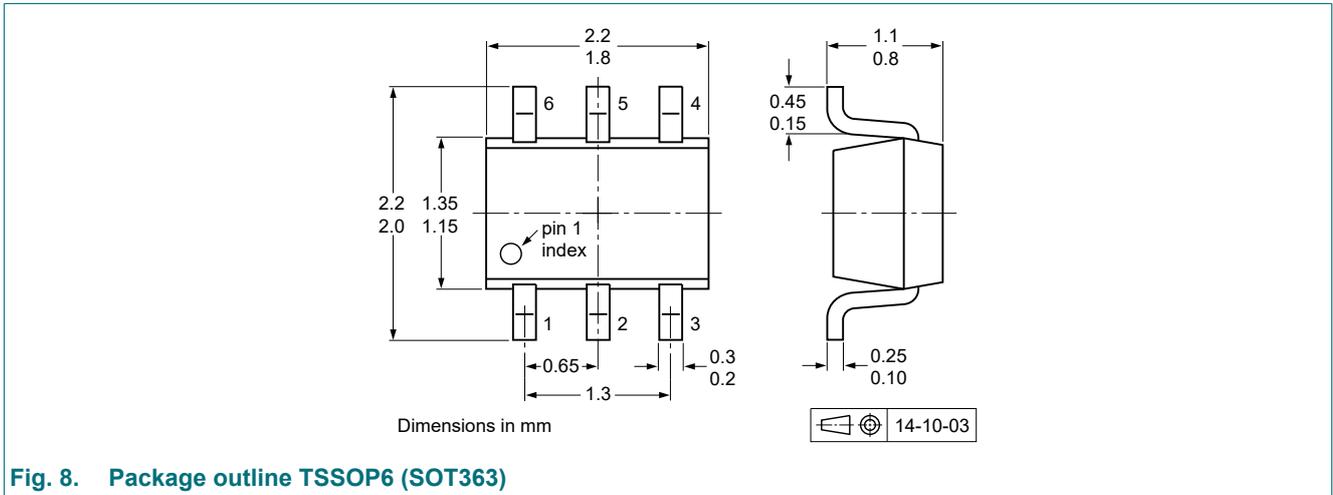


Fig. 8. Package outline TSSOP6 (SOT363)

## 13. Soldering

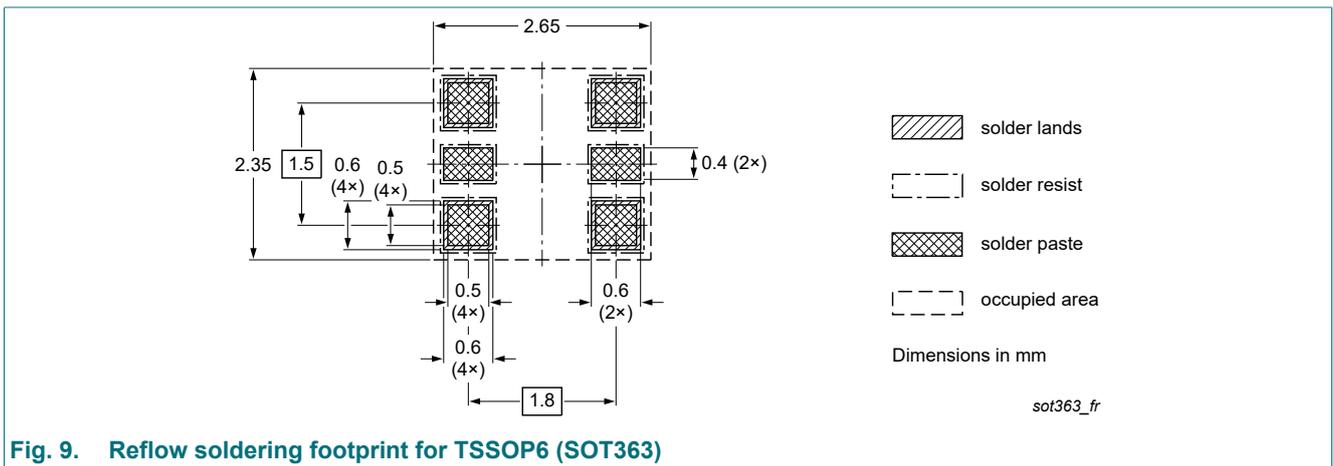


Fig. 9. Reflow soldering footprint for TSSOP6 (SOT363)

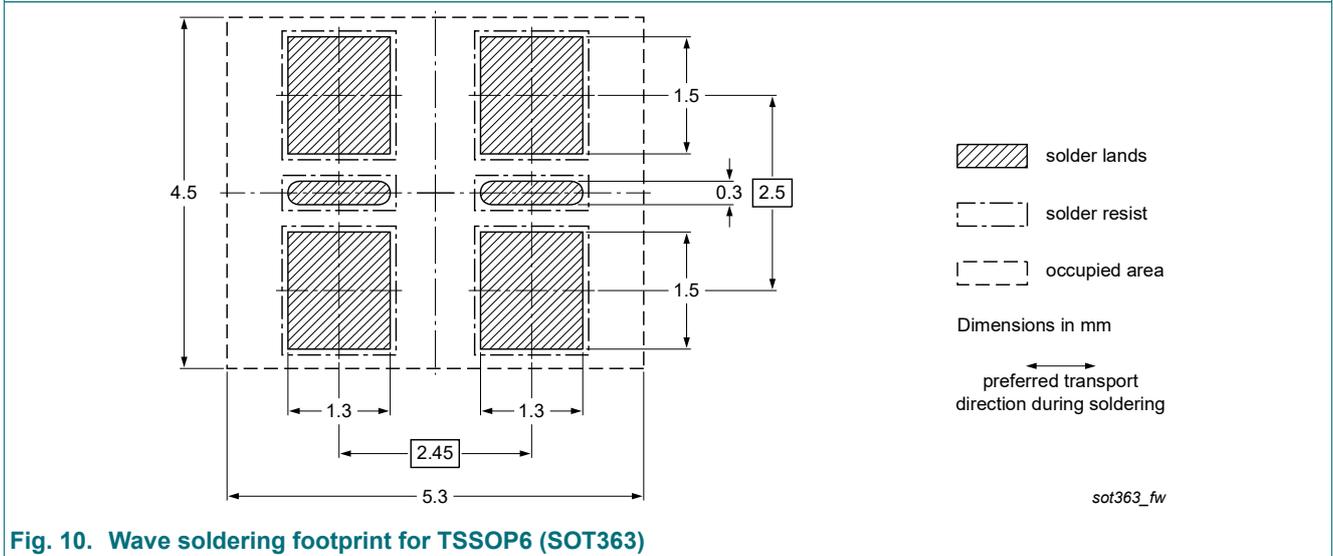


Fig. 10. Wave soldering footprint for TSSOP6 (SOT363)

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k $\Omega$ , R2 = 2.2 k $\Omega$ 

## 14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMH20 v.5	20230516	Product data sheet	-	PEMH20_PUMH20_4
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Family data sheet reduced to single type data sheet.</li> <li>Packing information removed.</li> </ul>			
PEMH20_PUMH20_4	20091115	Product data sheet	-	PEMH20_PUMH20_3
PEMH20_PUMH20_3	20050214	Product data sheet	-	PUMH20_2
PUMH20_2	20040414	Product specification	-	PUMH20_1
PUMH20_1	20031016	Product specification	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k $\Omega$ , R2 = 2.2 k $\Omega$

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